

2N3722

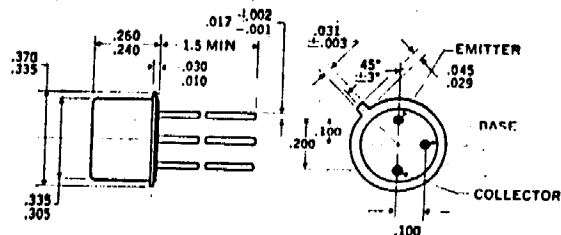
NPN SMALL SIGNAL HIGH VOLTAGE HIGH CURRENT SWITCHES

- $V_{CE0} \dots 60 \text{ V (MIN.) (2N3722)}$
- $h_{FE} \dots 40 - 150 @ 100 \text{ mA}$
 $\dots 12 \text{ (MIN.) @ 800 mA}$
- $t_{on} \dots 50 \text{ ns (MAX.) @ 500 mA (2N3722)}$
- $t_{off} \dots 100 \text{ ns (MAX.) @ 500 mA (2N3722)}$

ABSOLUTE MAXIMUM RATINGS

Maximum Temperatures	
Storage Temperature	-65°C to +200°C
Operating Junction Temperature	200°C
Lead Temperature (60 seconds)	300°C
Maximum Power Dissipation	
Total Dissipation at 25°C Case Temperature	4.0 W
at 25°C Ambient Temperature	0.8 W
Maximum Voltages and Current	2N3722
V_{CBO} Collector to Base Voltage	80 V
V_{CES} Collector to Emitter Voltage	80 V
V_{CEO} Collector to Emitter Voltage	60 V
V_{EBO} Emitter to Base Voltage	6.0 V
I_C Collector Current	1.0 A

MECHANICAL SPECIFICATIONS



Dimensions in inches.

ELECTRICAL CHARACTERISTICS (25°C Ambient Temperature unless otherwise noted)

SYMBOL	CHARACTERISTIC	2N3722		UNITS	TEST CONDITIONS
		MIN.	MAX.		
$V_{CE0(sus)}$	Collector to Emitter Sustaining Voltage	60		V	$I_C = 10 \text{ mA (pulsed)}, I_B = 0$
$V_{CE(sat)}$	Collector to Emitter Saturation Voltage	0.25		V	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$
		0.22		V	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$
		0.37		V	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$
		0.50		V	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$
		2.0		V	$I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$
t_{on}	Turn On Time (see test circuit no. 265)		50	ns	$I_C \approx 500 \text{ mA}, I_{B1} \approx 50 \text{ mA}$
t_{off}	Turn Off Time (see test circuit no. 265)		100	ns	$I_C \approx 500 \text{ mA}, I_{B1} \approx I_{B2} \approx 50 \text{ mA}$
C_{ob}	Output Capacitance		10	pF	$I_E = 0, V_{CB} = 10 \text{ V}$
C_{ib}	Input Capacitance		65	pF	$V_{EB} = 0.5 \text{ V}, I_C = 0$
h_{FE}	DC Current Gain	25			$I_C = 10 \text{ mA}, V_{CE} = 1.0 \text{ V}$
		40	150		$I_C = 100 \text{ mA}, V_{CE} = 1.0 \text{ V}$
		20			$I_C = 300 \text{ mA}, V_{CE} = 2.0 \text{ V}$
		15			$I_C = 500 \text{ mA}, V_{CE} = 2.0 \text{ V}$
		12			$I_C = 800 \text{ mA}, V_{CE} = 5.0 \text{ V}$
$V_{BE(sat)}$	Base to Emitter Saturation Voltage		0.75	V	$I_C = 10 \text{ mA}, I_B = 1.0 \text{ mA}$
			0.85	V	$I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$
			1.1	V	$I_C = 300 \text{ mA}, I_B = 30 \text{ mA}$
		0.88	1.2	V	$I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$
			1.5	V	$I_C = 800 \text{ mA}, I_B = 80 \text{ mA}$
h_{fe}	High Frequency Current Gain	3.0			$I_C = 50 \text{ mA}, V_{CE} = 10 \text{ V}, f = 100 \text{ MHz}$
I_{CES}	Collector Reverse Current		500	nA	$V_{CE} = 40 \text{ V}, V_{EB} = 0$
			70	μA	$V_{CE} = 40 \text{ V}, V_{EB} = 0, T_A = 125^\circ\text{C}$
BV_{CBO}	Collector to Base Breakdown Voltage	80		V	$I_C = 100 \mu\text{A}, I_E = 0$
BV_{CES}	Collector to Emitter Breakdown Voltage	80		V	$I_C = 100 \mu\text{A}, V_{EB} = 0$
BV_{EBO}	Emitter to Base Breakdown Voltage	6.0		V	$I_E = 100 \mu\text{A}, I_C = 0$

